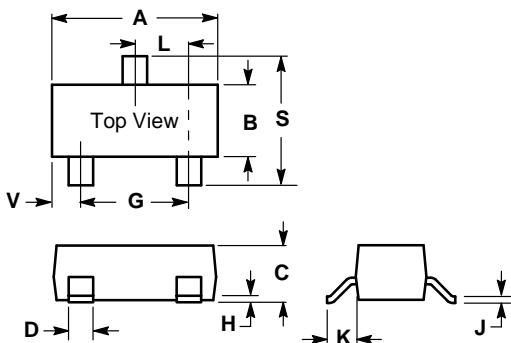
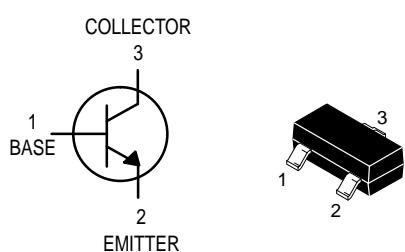


RoHS Compliant Product



SOT-323		
Dim	Min	Max
A	1.800	2.200
B	1.150	1.350
C	0.800	1.000
D	0.300	0.400
G	1.200	1.400
H	0.000	0.100
J	0.100	0.250
K	0.350	0.500
L	0.590	0.720
S	2.000	2.400
V	0.280	0.420

All Dimension in mm

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	40	Vdc
Collector-Base Voltage	$V_{CBO}$	60	Vdc
Emitter-Base Voltage	$V_{EBO}$	6.0	Vdc
Collector Current — Continuous	$I_C$	600	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board(1) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	200	mW
		1.8	$\text{mW}/^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate,(2) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	200	mW
		2.4	$\text{mW}/^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

#### DEVICE MARKING

MMBT4401W = K3X, 2X

#### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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#### OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage <sup>(3)</sup> ( $I_C = 1.0 \text{ mA}, I_B = 0$ )	$V_{(BR)CEO}$	40	—	Vdc
Collector-Base Breakdown Voltage ( $I_C = 0.1 \text{ mA}, I_E = 0$ )	$V_{(BR)CBO}$	60	—	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 0.1 \text{ mA}, I_C = 0$ )	$V_{(BR)EBO}$	6.0	—	Vdc
Base Cutoff Current ( $V_{CE} = 35 \text{ Vdc}, V_{EB} = 0.4 \text{ Vdc}$ )	$I_{BEV}$	—	0.1	$\mu\text{Adc}$
Collector Cutoff Current ( $V_{CE} = 35 \text{ Vdc}, V_{EB} = 0.4 \text{ Vdc}$ )	$I_{CEX}$	—	0.1	$\mu\text{Adc}$

- FR-5 =  $1.0 \times 0.75 \times 0.062 \text{ in.}$
- Alumina =  $0.4 \times 0.3 \times 0.024 \text{ in.}$  99.5% alumina.
- Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

**ELECTRICAL CHARACTERISTICS** (continued) ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>ON CHARACTERISTICS<sup>(3)</sup></b>				
DC Current Gain ( $I_C = 0.1 \text{ mA}_\text{dc}$ , $V_{CE} = 1.0 \text{ V}_\text{dc}$ ) ( $I_C = 1.0 \text{ mA}_\text{dc}$ , $V_{CE} = 1.0 \text{ V}_\text{dc}$ ) ( $I_C = 10 \text{ mA}_\text{dc}$ , $V_{CE} = 1.0 \text{ V}_\text{dc}$ ) ( $I_C = 150 \text{ mA}_\text{dc}$ , $V_{CE} = 1.0 \text{ V}_\text{dc}$ ) ( $I_C = 500 \text{ mA}_\text{dc}$ , $V_{CE} = 2.0 \text{ V}_\text{dc}$ )	$h_{FE}$	20 40 80 100 40	— — — 300 —	—
Collector-Emitter Saturation Voltage ( $I_C = 150 \text{ mA}_\text{dc}$ , $I_B = 15 \text{ mA}_\text{dc}$ ) ( $I_C = 500 \text{ mA}_\text{dc}$ , $I_B = 50 \text{ mA}_\text{dc}$ )	$V_{CE(\text{sat})}$	— —	0.4 0.75	$\text{V}_\text{dc}$
Base-Emitter Saturation Voltage ( $I_C = 150 \text{ mA}_\text{dc}$ , $I_B = 15 \text{ mA}_\text{dc}$ ) ( $I_C = 500 \text{ mA}_\text{dc}$ , $I_B = 50 \text{ mA}_\text{dc}$ )	$V_{BE(\text{sat})}$	0.75 —	0.95 1.2	$\text{V}_\text{dc}$

**SMALL-SIGNAL CHARACTERISTICS**

Current-Gain — Bandwidth Product ( $I_C = 20 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ V}_\text{dc}$ , $f = 100 \text{ MHz}$ )	$f_T$	250	—	MHz
Collector-Base Capacitance ( $V_{CB} = 5.0 \text{ V}_\text{dc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{cb}$	—	6.5	pF
Emitter-Base Capacitance ( $V_{EB} = 0.5 \text{ V}_\text{dc}$ , $I_C = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{eb}$	—	30	pF
Input Impedance ( $I_C = 1.0 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ V}_\text{dc}$ , $f = 1.0 \text{ kHz}$ )	$h_{ie}$	1.0	15	k $\Omega$
Voltage Feedback Ratio ( $I_C = 1.0 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ V}_\text{dc}$ , $f = 1.0 \text{ kHz}$ )	$h_{re}$	0.1	8.0	$\times 10^{-4}$
Small-Signal Current Gain ( $I_C = 1.0 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ V}_\text{dc}$ , $f = 1.0 \text{ kHz}$ )	$h_{fe}$	40	500	—
Output Admittance ( $I_C = 1.0 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ V}_\text{dc}$ , $f = 1.0 \text{ kHz}$ )	$h_{oe}$	1.0	30	$\mu\text{mhos}$

**SWITCHING CHARACTERISTICS**

Delay Time	$(V_{CC} = 30 \text{ V}_\text{dc}$ , $V_{EB} = 2.0 \text{ V}_\text{dc}$ , $I_C = 150 \text{ mA}_\text{dc}$ , $I_{B1} = 15 \text{ mA}_\text{dc}$ )	$t_d$	—	15	ns
Rise Time		$t_r$	—	20	
Storage Time	$(V_{CC} = 30 \text{ V}_\text{dc}$ , $I_C = 150 \text{ mA}_\text{dc}$ , $I_{B1} = I_{B2} = 15 \text{ mA}_\text{dc}$ )	$t_s$	—	225	ns
Fall Time		$t_f$	—	30	

3. Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

**SWITCHING TIME EQUIVALENT TEST CIRCUITS**

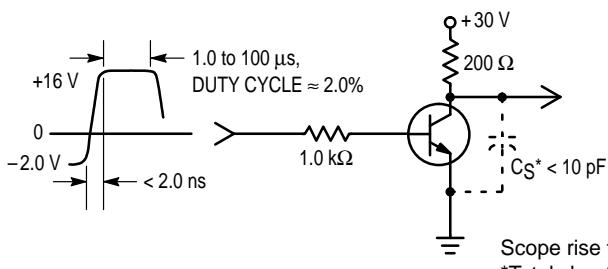


Figure 1. Turn-On Time

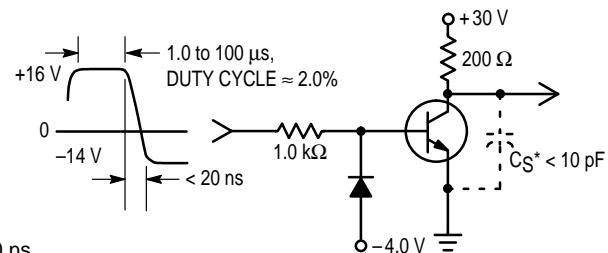


Figure 2. Turn-Off Time

### TRANSIENT CHARACTERISTICS

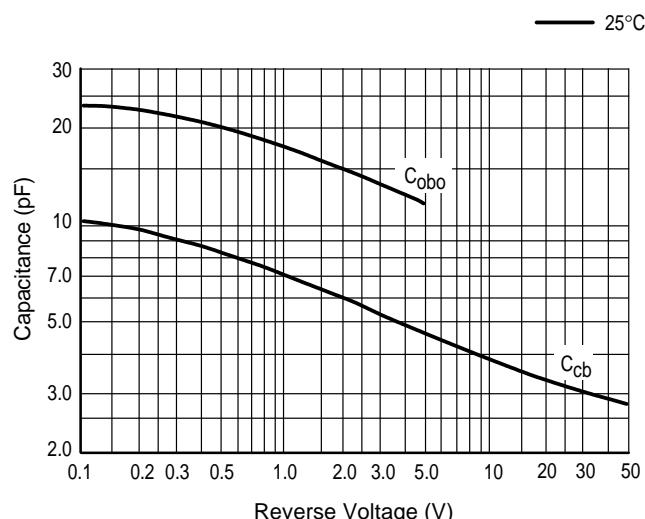


Figure 3. Capacitances

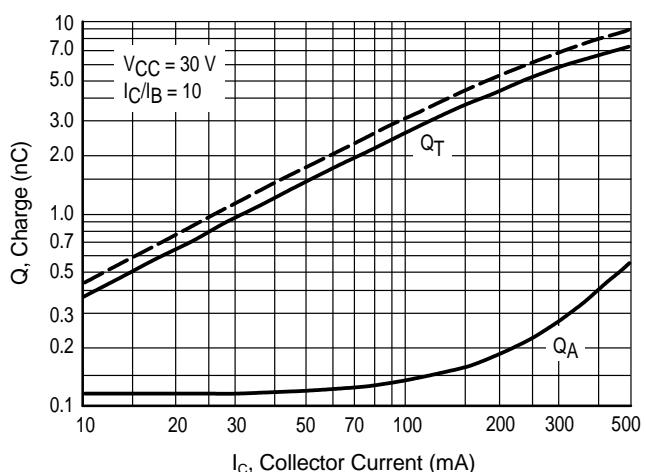


Figure 4. Charge Data

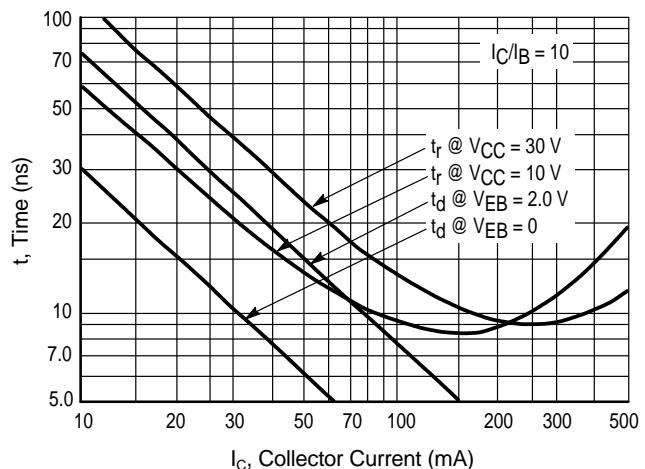


Figure 5. Turn-On Time

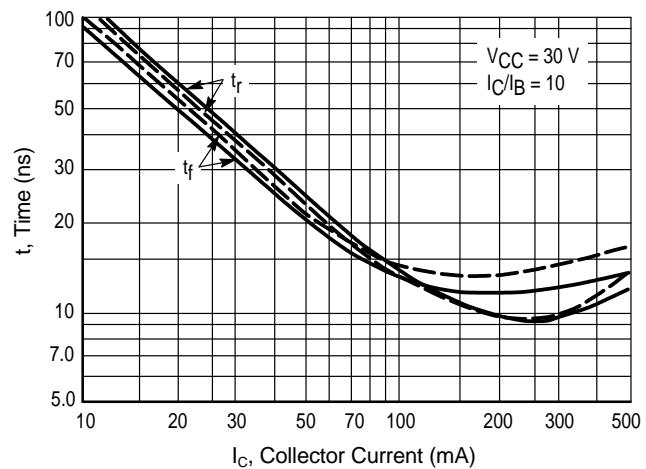


Figure 6. Rise and Fall Times

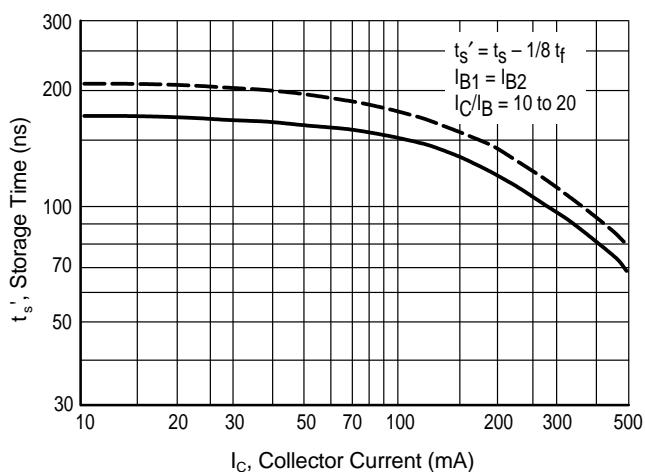


Figure 7. Storage Time

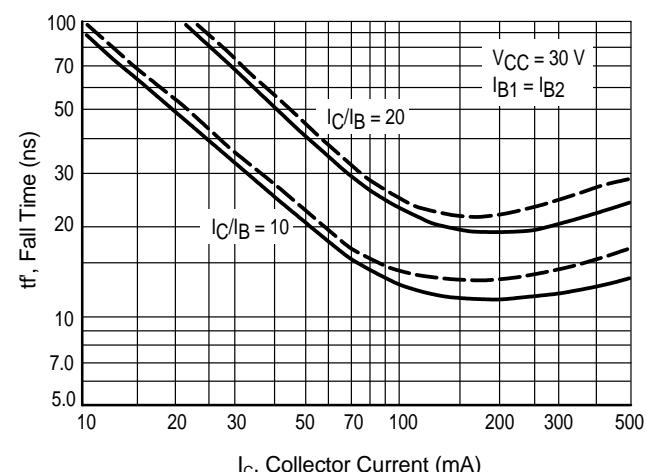
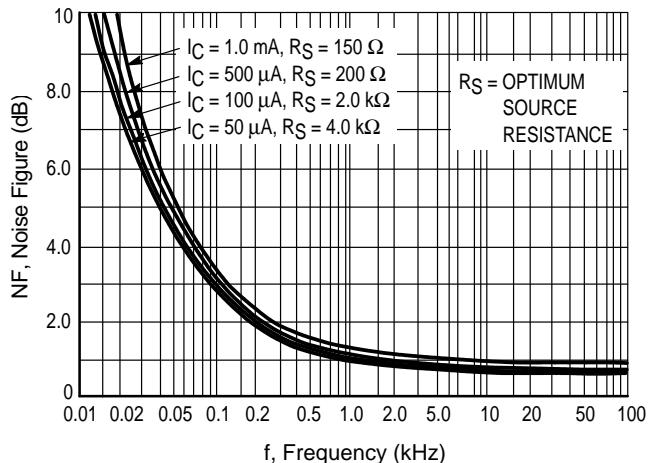
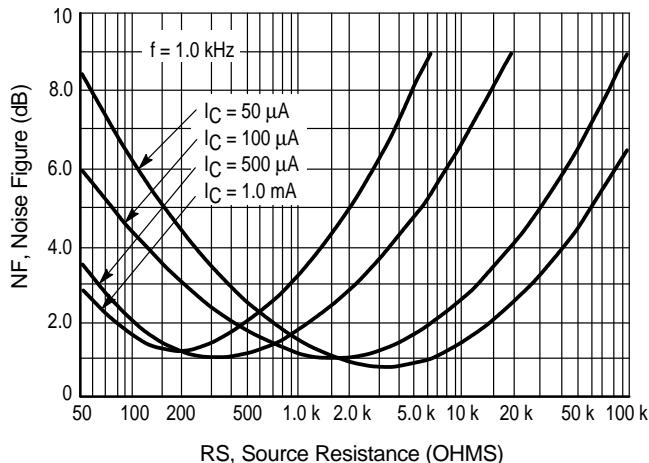


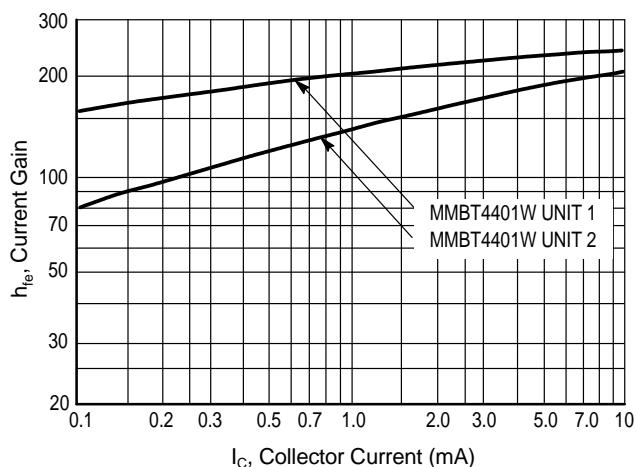
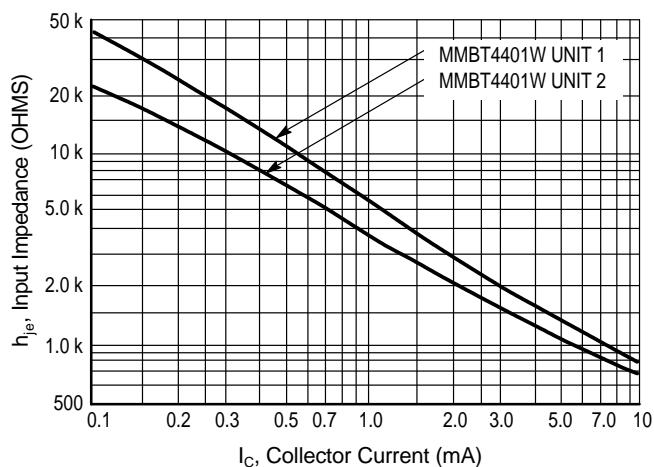
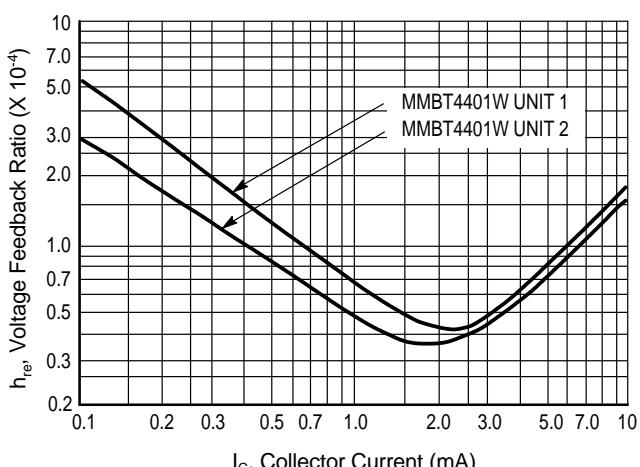
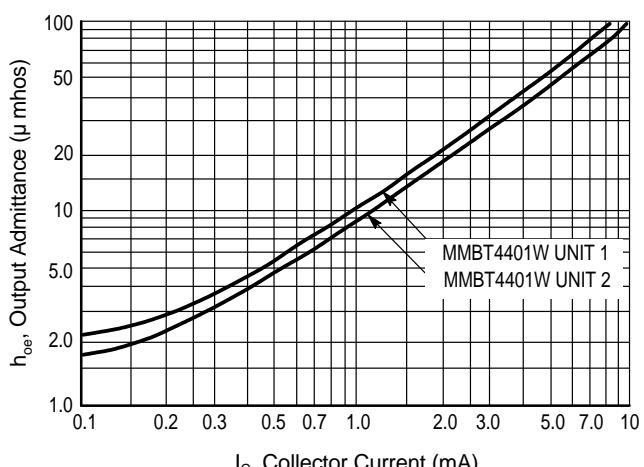
Figure 8. Fall Time

**SMALL-SIGNAL CHARACTERISTICS**
**NOISE FIGURE**
 $V_{CE} = 10 \text{ Vdc}$ ,  $T_A = 25^\circ\text{C}$ 

Bandwidth = 1.0 Hz


**Figure 9. Frequency Effects**

**Figure 10. Source Resistance Effects**
 **$h$  PARAMETERS**
 $V_{CE} = 10 \text{ Vdc}$ ,  $f = 1.0 \text{ kHz}$ ,  $T_A = 25^\circ\text{C}$ 

This group of graphs illustrates the relationship between  $h_{fe}$  and other "h" parameters for this series of transistors. To obtain these curves, a high-gain and a low-gain unit were selected from the MMBT4401W lines, and the same units were used to develop the correspondingly numbered curves on each graph.


**Figure 11. Current Gain**

**Figure 12. Input Impedance**

**Figure 13. Voltage Feedback Ratio**

**Figure 14. Output Admittance**

Any changing of specification will not be informed individual

**STATIC CHARACTERISTICS**

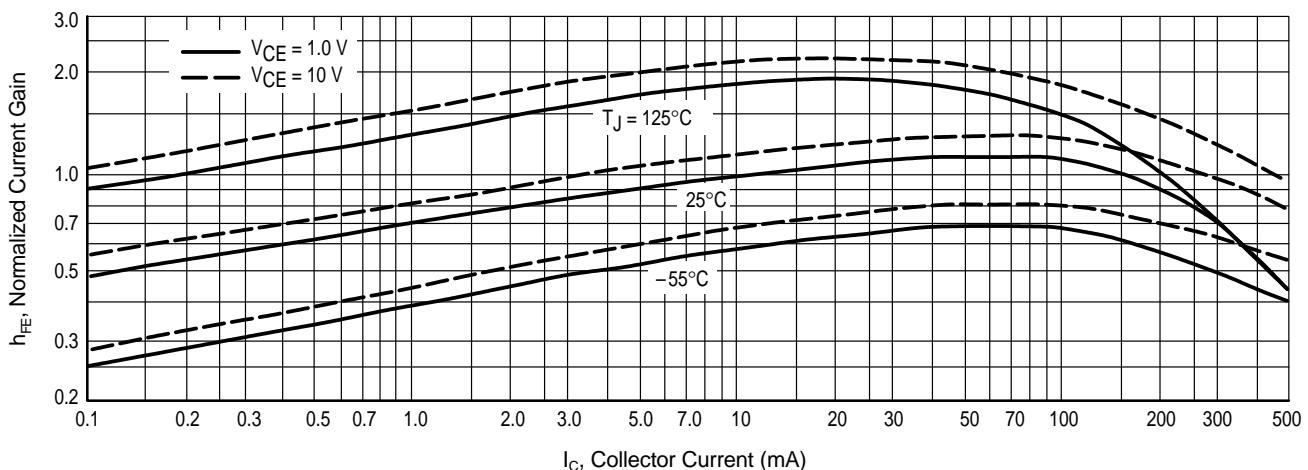


Figure 15. DC Current Gain

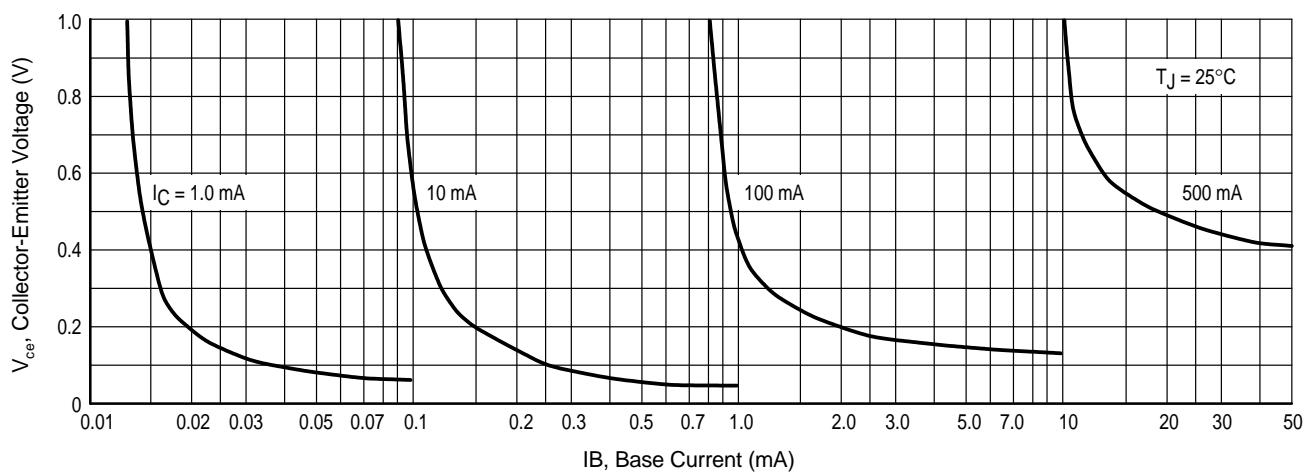


Figure 16. Collector Saturation Region

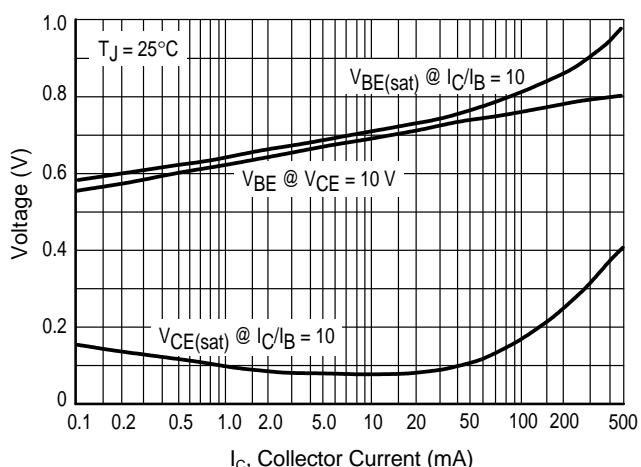


Figure 17. "On" Voltages

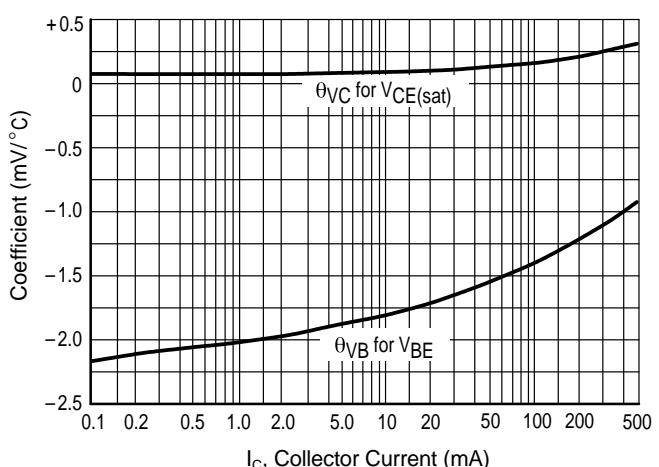


Figure 18. Temperature Coefficients